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Important notice

Dear Customer,

On 7 February 2017 the former NXP Standard Product business became a new company with the tradename **Nexperia**. Nexperia is an industry leading supplier of Discrete, Logic and PowerMOS semiconductors with its focus on the automotive, industrial, computing, consumer and wearable application markets

In data sheets and application notes which still contain NXP or Philips Semiconductors references, use the references to Nexperia, as shown below.

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If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

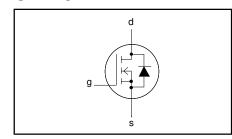
N-channel TrenchMOSTM transistor Logic level FET

BSS123

FEATURES

- 'Trench' technology
- Extremely fast switching
- Logic level compatible
- Subminiature surface mounting package

SYMBOL



QUICK REFERENCE DATA

$$V_{DSS} = 100 \text{ V}$$

$$I_D = 150 \text{ mA}$$

$$R_{DS(ON)} \le 6 \Omega \text{ (V}_{GS} = 10 \text{ V)}$$

GENERAL DESCRIPTION

N-channel enhancement mode field-effect transistor in a plastic envelope using 'trench' technology.

Applications:-

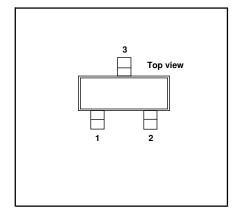
- Relay driver
- High-speed line driver
- Telephone ringer

The BSS123 is supplied in the SOT23 subminiature surface mounting package.

PINNING

PIN	DESCRIPTION	
1	gate	
2	source	
3	drain	

SOT23



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DSS} V _{DGR} V _{GS} I _D	Drain-source voltage Drain-gate voltage Gate-source voltage Continuous drain current Pulsed drain current	$T_j = 25$ °C to 150°C $T_j = 25$ °C to 150°C; $R_{GS} = 20$ kΩ $T_a = 25$ °C $T_a = 25$ °C $T_a = 25$ °C	- - - -	100 100 ± 20 150 600	V V MA mA
P_{D} T_{j} , T_{stg}	Total power dissipation Operating junction and storage temperature	T _a = 25 °C	- - 55	0.25 150	°C W

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
R _{th j-a}	Thermal resistance junction to ambient	surface mounted on FR4 board	500	-	K/W

N-channel TrenchMOS $^{\mathrm{TM}}$ transistor Logic level FET

BSS123

ELECTRICAL CHARACTERISTICS

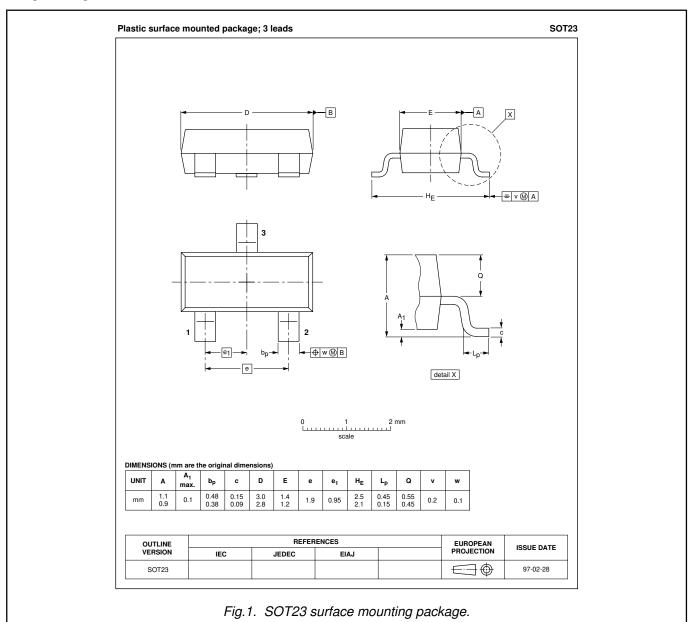
 T_{j} = 25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{(BR)DSS}$	Drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_{D} = 10 \mu\text{A}$	100	130	1	٧
V _{GS(TO)}	Gate threshold voltage	$V_{DS} = V_{GS}$; $I_D = 1 \text{ mA}$	1	2	2.8	V
$R_{DS(ON)}$	Drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_{D} = 120 \text{ mA}$	1	3.5	6	Ω
g_{fs}	Forward transconductance	$V_{DS} = 25 \text{ V}; I_{D} = 120 \text{ mA}$	ı	350	-	mS
I _{DSS}	Zero gate voltage drain current	$V_{DS} = 60 \text{ V}; V_{GS} = 0 \text{ V}$	-	10	100	nA
I _{GSS}	Gate source leakage current	$V_{GS} = \pm 20 \text{ V}; V_{DS} = 0 \text{ V}$	-	10	100	nA
t _{on}	Turn-on time	V_{DD} = 50 V; R_D = 250 Ω ; V_{GS} = 10 V; R_G = 50 Ω ; Resistive load	-	3	10	ns
t_{off}	Turn-off time	,	-	12	20	ns
C _{iss}	Input capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 25 \text{ V}; f = 1 \text{ MHz}$	-	23	40	рF
Coss	Output capacitance		-	6	25	pF
C_{rss}	Feedback capacitance		-	4	10	pF

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MECHANICAL DATA



Notes

- 1. This product is supplied in anti-static packaging. The gate-source input must be protected against static discharge during transport or handling.
- 2. Refer to SMD Footprint Design and Soldering Guidelines, Data Handbook SC18.
- 3. Epoxy meets UL94 V0 at 1/8".

N-channel TrenchMOSTM transistor Logic level FET

BSS123

DEFINITIONS

Data sheet status			
Objective specification This data sheet contains target or goal specifications for product development.			
Preliminary specification This data sheet contains preliminary data; supplementary data may be published			
Product specification	This data sheet contains final product specifications.		
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Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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